

| L Number | Hits | Search Text | DB | Time stamp |
|----------|------|---|---|------------------|
| - | 146 | (423/346).CCLS. | USPAT; US-PGPUB | 2003/11/03 11:50 |
| - | 551 | (423/345,346).CCLS. | USPAT; US-PGPUB | 2003/11/03 11:51 |
| - | 20 | ((423/346).CCLS.) and conductivity | USPAT; US-PGPUB | 2003/11/03 11:51 |
| - | 4 | ((423/346).CCLS.) and conductivity with (w or mk or "w/mk") | USPAT; US-PGPUB | 2003/11/03 11:55 |
| - | 4 | ((423/346).CCLS.) and conductivity) and conductivity with (w or mk or "w/mk") | USPAT; US-PGPUB | 2003/11/03 12:02 |
| - | 629 | ((silicon adj carbide) or sic) same (conductivity with (w or mk or "w/mk")) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/11/03 12:03 |
| - | 198 | ((silicon adj carbide) or sic) same (conductivity with (w or mk or "w/mk"))) and (cvd or (chemical adj vapor)) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/11/03 13:09 |
| - | 62 | (cvd or (chemical adj vapor)) same ((silicon adj carbide) or sic) same (conductivity with (w or mk or "w/mk")) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/11/03 12:06 |
| - | 62 | (cvd or (chemical adj vapor)) same ((silicon adj carbide) or sic) same (conductivity with (kw or w or mk or "w/mk")) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/11/03 12:07 |
| - | 62 | (cvd or (chemical adj vapor)) same ((silicon adj carbide) or sic) same (conductivity with (kw or w or mk or "w/mk" or "kw/mk")) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/11/03 13:14 |
| - | 198 | (cvd or (chemical adj vapor)) and ((silicon adj carbide) or sic) same (conductivity with (kw or w or mk or "w/mk" or "kw/mk")) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/11/03 13:04 |
| - | 9 | ((cvd or (chemical adj vapor)) and ((silicon adj carbide) or sic) same (conductivity with (kw or w or mk or "w/mk" or "kw/mk"))) and polycrystalline with phase | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/11/03 12:16 |
| - | 54 | ((cvd or (chemical adj vapor)) and ((silicon adj carbide) or sic) same (conductivity with (kw or w or mk or "w/mk" or "kw/mk"))) and (beta or ".beta.sic" or ".beta."\$4) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/11/03 12:17 |
| - | 198 | (cvd or (chemical adj vapor)) and ((silicon adj carbide) or sic) same (conductivity with (kw or w or mk or "w/mk" or "kw/mk")) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/11/03 13:09 |
| - | 8 | ((cvd or (chemical adj vapor)) and ((silicon adj carbide) or sic) same (conductivity with (kw or w or mk or "w/mk" or "kw/mk"))) and order with ratio | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/11/03 13:08 |
| - | 3 | ((cvd or (chemical adj vapor)) and ((silicon adj carbide) or sic) same (conductivity with (kw or w or mk or "w/mk" or "kw/mk"))) and crystalline with ratio | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/11/03 13:08 |
| - | 7 | ((cvd or (chemical adj vapor)) and ((silicon adj carbide) or sic) same (conductivity with (kw or w or mk or "w/mk" or "kw/mk"))) and crystalline with order | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/11/03 13:08 |

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|---|---------|---|---|------------------|
| - | 1 | (cvd or (chemical adj vapor)) and ((silicon adj carbide) or sic) same (\$4crystalline with (order adj ratio)) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/11/03 13:13 |
| - | 1 | (cvd or (chemical adj vapor)) and ((silicon adj carbide) or sic) same (order adj ratio)) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/11/03 13:11 |
| - | 1 | (cvd or (chemical adj vapor)) and ((silicon adj carbide) or sic) and (\$4crystalline with (order adj ratio)) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/11/03 13:11 |
| - | 8 | (cvd or (chemical adj vapor)) and ((silicon adj carbide) or sic) and (order adj ratio) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/11/03 13:12 |
| - | 4 | ((cvd or (chemical adj vapor)) and ((silicon adj carbide) or sic) same (conductivity with (kw or w or mk or "w/mk" or "kw/mk"))) and (stacking adj fault) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/11/03 13:14 |
| - | 4 | ((cvd or (chemical adj vapor)) and ((silicon adj carbide) or sic) same (conductivity with (kw or w or mk or "w/mk" or "kw/mk"))) and (stack\$3 adj fault) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/11/03 13:14 |
| - | 62 | (cvd or (chemical adj vapor)) same ((silicon adj carbide) or sic) same (conductivity with (kw or w or mk or "w/mk" or "kw/mk")) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/11/03 13:46 |
| - | 13 | ((cvd or (chemical adj vapor)) same ((silicon adj carbide) or sic) same (conductivity with (kw or w or mk or "w/mk" or "kw/mk"))) and (defect or fault) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/11/03 13:15 |
| - | 3 | ((cvd or (chemical adj vapor)) same ((silicon adj carbide) or sic) same (conductivity with (kw or w or mk or "w/mk" or "kw/mk"))) and fault | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/11/03 13:16 |
| - | 16 | ((cvd or (chemical adj vapor)) same ((silicon adj carbide) or sic) same (conductivity with (kw or w or mk or "w/mk" or "kw/mk"))) and stack\$3 | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/11/03 13:16 |
| - | 4 | ((cvd or (chemical adj vapor)) and ((silicon adj carbide) or sic) same (conductivity with (kw or w or mk or "w/mk" or "kw/mk"))) and (stack\$3 with fault\$1) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/11/03 13:17 |
| - | 10 | ((cvd or (chemical adj vapor)) same ((silicon adj carbide) or sic) same (conductivity with (kw or w or mk or "w/mk" or "kw/mk"))) and mandrel | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/11/03 13:47 |
| - | 2217297 | ((cvd or (chemical adj vapor)) same ((silicon adj carbide) or sic) same (conductivity with (kw or w or mk or "w/mk" or "kw/mk"))) and mandrel) parallel | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/11/03 13:47 |
| - | 1 | ((cvd or (chemical adj vapor)) same ((silicon adj carbide) or sic) same (conductivity with (kw or w or mk or "w/mk" or "kw/mk"))) and mandrel) and parallel | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/11/03 13:47 |